

## OPTICAL AND ELECTRICAL PROPERTIES

### OF $\text{Co}_3(\text{BO}_3)_2$ AND $\text{Ni}_3(\text{BO}_3)_2$

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The paper presents the results of investigation of some physical properties of Co and Ni-borate. The crystal structure and magnetic properties have been described earlier. In the present investigation the optical spectra in the visible region are recorded and electrical conductivities and dielectric permittivities are measured.

#### INTRODUCTION

The crystal structure of borates  $\text{Co}(\text{BO}_3)_2$  and  $\text{Ni}(\text{BO}_3)_2$  are known [1, 2, 3], Besides, the magnetic properties and the magnetic structure of these compounds are determined [3,4]. In the crystals of these borates the  $\text{Co}^{2+}$  and  $\text{Ni}^{2+}$ -ions are surrounded by the coordination octahedra formed by the O-atoms from  $\text{BO}_3^{3-}$ -ions. This is new investigation which gives additional information on the properties of the  $\text{Co}^{2+}$  and  $\text{Ni}^{2+}$  ions in such surrounding.

The synthesis of these compounds is accomplished by the procedure described in [3]. The polycrystalline samples obtained are identified by the method of x-ray diffraction.

#### OPTICAL SPECTRA

The optical spectra of  $\text{Co}_3(\text{BO}_3)_2$  and  $\text{Ni}_3(\text{BO}_3)_2$  in the region of wavelengths from 350 to 1000 nm are recorded by the method of diffuse reflection spectrophotometry (figs. 1. and 2.). The interpretation of these spectra is made by the use of the Tanabe-Sugano method [5]. The results of the assigned electronic transition are given on table 1.

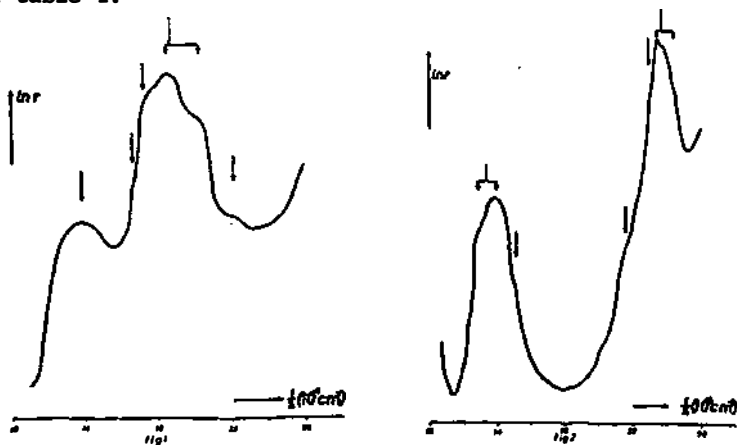
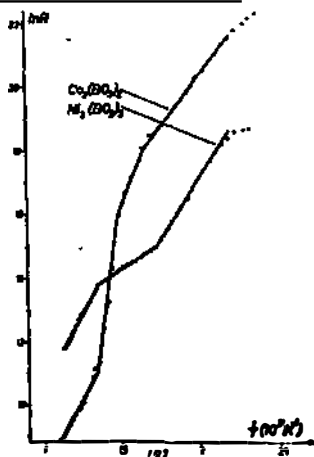


Table 1. Electronic transitions, their energies and values of  $\beta$  and  $10 Dq$  for the recorded spectra

fig. 1.: $\text{Co}_3(\text{BO}_3)_2$		fig. 2.: $\text{Ni}_3(\text{BO}_3)_2$	
transition	energy ( $\text{cm}^{-1}$ )	transition	energy ( $\text{cm}^{-1}$ )
$4T_{1g}(^4F) \rightarrow 4A_{2g}$	13950	$3A_{2g}(^3F) \rightarrow 3T_{1g}(^3F)$	13300
$2T_{1g}$	16600	$1E_g$	15700
$2T_{2g}$	17250	$1T_{2g}$	21600
$4T_{1g}(^4P)$	18650	$1T_{1g}$	23000
$2A_{1g}$	22200	$3T_{1g}(^3P)$	23800
$\beta$	0,89	$\beta$	0,85
$10 Dq$	$7200 \text{ cm}^{-1}$	$10 Dq$	$7650 \text{ cm}^{-1}$

The calculated electronic transitions are indicated in figs. 1. and 2. by arrows. On table 1. the values for the bond character coefficient  $\beta$  and for the crystal field parameter  $10 Dq$  are given also. These values correspond to those obtained for the octahedral complexes  $\text{Co}_6$  and  $\text{NiO}_6$  in other compounds [6].

#### ELECTRICAL CONDUCTIVITIES



The dependence of the electrical resistance ( $R$ ) temperature is measured by the use of a digital electrometer. The measurements are performed for the temperature range 300 - 800 K (fig. 3). The dependence  $\ln R$  on  $1/T$  for both compounds is characterized by the existence of narrow temperature regions with different activation energies ( $E$ ). The limits of these regions and the corresponding values of activation energies are given on table 2

On the basis of the realized experiments it is difficult to conclude what kind of microscopic processes are responsible for this sort of dependence  $R(T)$ . For the time being it is sure only that the similar changes are found in the investigation of dielectric properties of these compounds (fig. 4.)

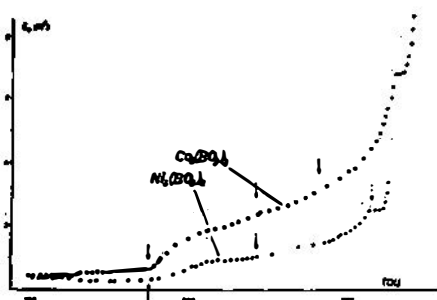
Table 2. Activation energies E for the dependence R(T)					
Co <sub>3</sub> (BO <sub>3</sub> ) <sub>2</sub>			Ni <sub>3</sub> (BO <sub>3</sub> ) <sub>2</sub>		
region limits		E (eV)	region limits		E (eV)
1/T (10 <sup>3</sup> K)	T (K)		1/T (10 <sup>3</sup> K)	T (K)	
2,2	454	0,55	2,2	454	0,63
1,68	595		1,71	584	
1,68	595	1,0	1,71	584	0,28
1,48	676		1,345	743	
1,48	676	3,15	1,345	743	
1,345	743	0,86	<1,345	>743	0,74
<1,345	>743		<1,345	>743	

#### DIELECTRIC PERMITTIVITIES

The dielectric permittivities ( $\epsilon_r$ ) measured by the use of one resonant bridge circuit (at 800 Hz) The results of these measurements performed during the heating up to  $T = 800$  K are presented in fig. 4. At room temperature for the Co - compound  $\epsilon_r = 50$  and for the Ni - compound  $\epsilon_r = 45$ . Steep increase of  $\epsilon_r$  is caused by heating. At  $T = 790$  K for Co - borate  $\epsilon_r = 850$ , and at  $T = 760$  K for Ni-borate  $\epsilon_r = 350$ . At higher temperatures the dielectric losses become too large to made the measurements by the used method reliable. In fig. 4. the arrows indicate the breaks in the parabolic shape of the dependence  $\epsilon_r(T)$ . These breaks lie at the temperatures which approximately correspond to the breaks in the dependence  $\ln R=f(1/T)$ .

#### FINAL REMARKS

For the explanation of experimentally obtained forms of dependences  $\epsilon_r(T)$  and  $R(T)$  the additional facts are necessary. The large values of  $\epsilon_r$  might be probably connected with large polarizability of the complexes  $\text{CoO}_6$  and  $\text{NiO}_6$  present in the structure of examined borates. Such properties have been predicted several years ago [7]. The actual origin of established properties will be investigated in the nearest future.



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